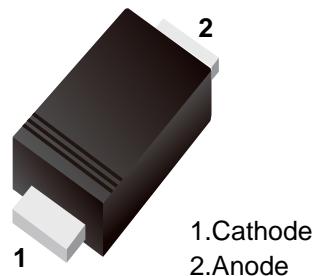


Surface Mount Schottky Barrier Rectifiers



■ Simplified outline(SOD-123FL)

Top View

■ FEATURES

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

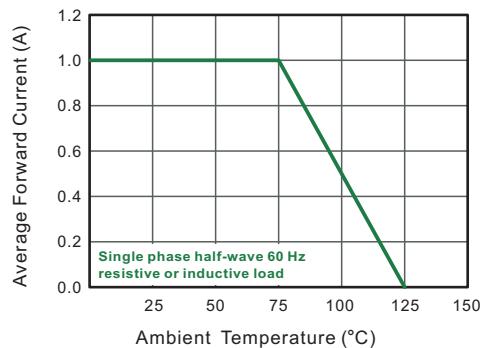
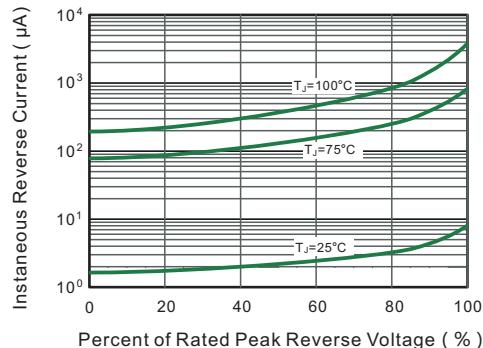
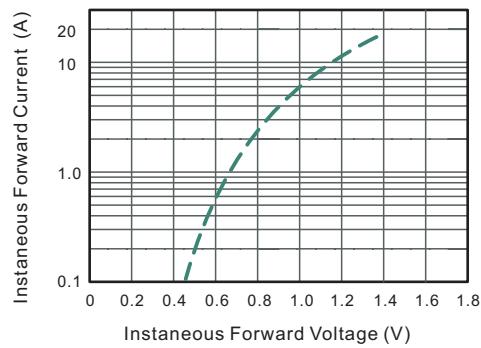
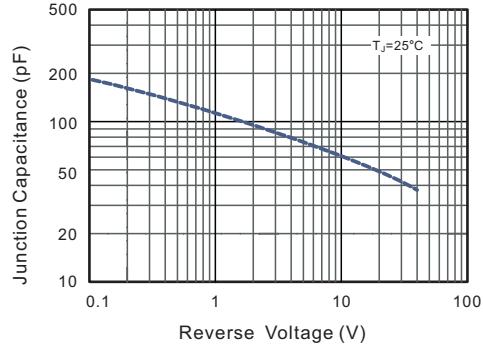
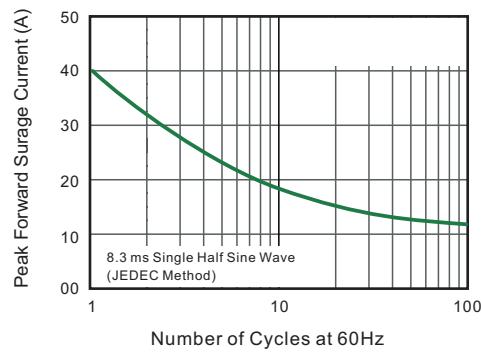
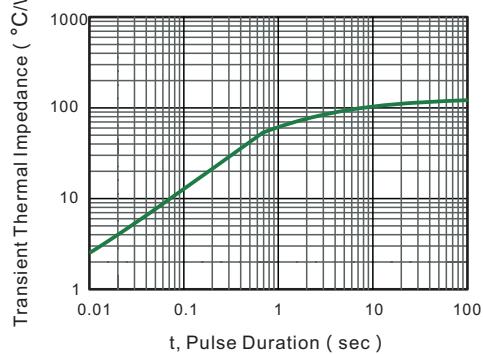
■ Absolute Maximum Ratings and Electrical characteristics

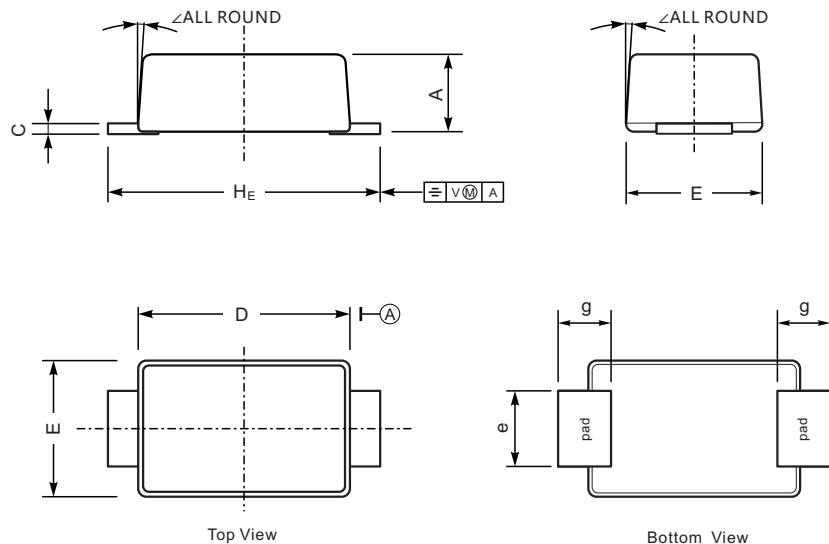
Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Parameter	Symbols	MBR0580	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	60	V
Maximum RMS voltage	V_{RMS}	42	V
Maximum DC Blocking Voltage	V_{DC}	60	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	1.0	A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	40	A
Max Instantaneous Forward Voltage at 1 A	V_F	0.70	V
Maximum DC Reverse Current $T_a = 25^\circ\text{C}$ at Rated DC Reverse Voltage $T_a = 100^\circ\text{C}$	I_R	0.3 10	mA
Typical Junction Capacitance ¹⁾	C_j	80	pF
Typical Thermal Resistance ²⁾	$R_{\theta JA}$	115	°C/W
Operating Junction Temperature Range	T_j	-55 ~ +125	°C
Storage Temperature Range	T_{stg}	-55 ~ +150	°C

1) Measured at 1MHz and applied reverse voltage of 4 V D.C.

2) P.C.B. mounted with 0.2 X 0.2" (5 X 5 mm) copper pad areas.

Fig.1 Forward Current Derating Curve**Fig.2 Typical Reverse Characteristics****Fig.3 Typical Forward Characteristic****Fig.4 Typical Junction Capacitance****Fig.5 Maximum Non-Repetitive Peak Forward Surge Current****Fig.6- Typical Transient Thermal Impedance**

■ SOD-123FL

UNIT		A	C	D	E	e	g	H _E	<
mm	max	1.1	0.20	2.9	1.9	1.1	0.9	3.8	7°
	min	0.9	0.12	2.6	1.7	0.8	0.7	3.5	
mil	max	43	7.9	114	75	43	35	150	7°
	min	35	4.7	102	67	31	28	138	

■ The recommended mounting pad size